

Silicon NPN Power Transistors

2SC4381 2SC4382

DESCRIPTION

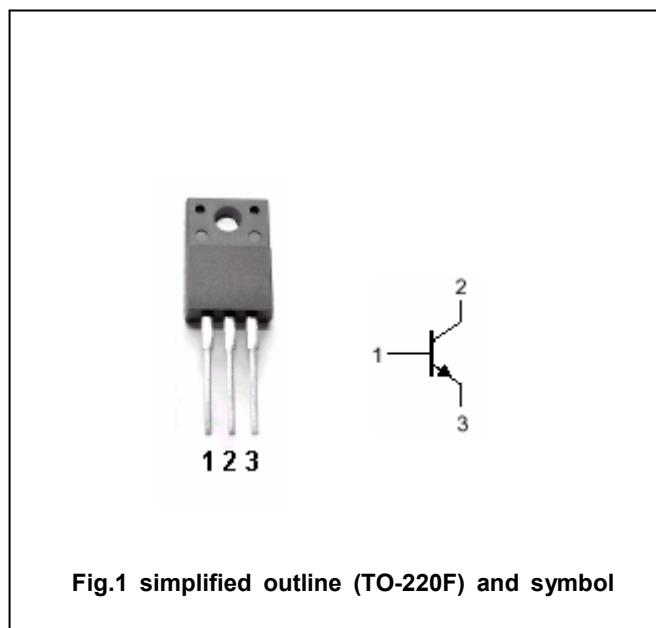
- With TO-220F package
- Complement to type 2SA1667/1668

APPLICATIONS

- For TV vertical output ,audio output driver and general purpose applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter

**Absolute maximum ratings (Ta=25℃)**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V _{CBO}	Collector-base voltage	2SC4381	150	V
		2SC4382	200	
V _{CEO}	Collector-emitter voltage	2SC4381	150	V
		2SC4382	200	
V _{EBO}	Emitter-base voltage	Open collector	6	V
I _C	Collector current		2	A
I _B	Base current		1	A
P _C	Collector dissipation	T _C =25℃	25	W
T _j	Junction temperature		150	℃
T _{stg}	Storage temperature		-55~150	℃

Silicon NPN Power Transistors

2SC4381 2SC4382

CHARACTERISTICS

Tj=25°C unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	2SC4381	$I_C=25mA ; I_B=0$	150			V
		2SC4382		200			
V_{CEsat}	Collector-emitter saturation voltage		$I_C=0.7A ; I_B=70mA$			1.0	V
I_{CBO}	Collector cut-off current	2SC4381	$V_{CB}=150V ; I_E=0$			10	μA
		2SC4382	$V_{CB}=200V ; I_E=0$			10	μA
I_{EBO}	Emitter cut-off current		$V_{EB}=6V ; I_C=0$			10	μA
h_{FE}	DC current gain		$I_C=0.7A ; V_{CE}=10V$	60			
f_T	Transition frequency		$I_C=0.2A ; V_{CE}=12V$		15		MHz
C_{OB}	Output capacitance		$I_E=0 ; V_{CB}=10V ; f=1MHz$		35		pF

Switching time

t_{on}	Turn-on time	$I_C=1A ; I_{B1}=-I_{B2}=0.1A$ $V_{CC}=20V , R_L=20\Omega$		1.0		μs
t_s	Storage time			3.0		μs
t_f	Fall time			1.5		μs

Silicon NPN Power Transistors

2SC4381 2SC4382

PACKAGE OUTLINE

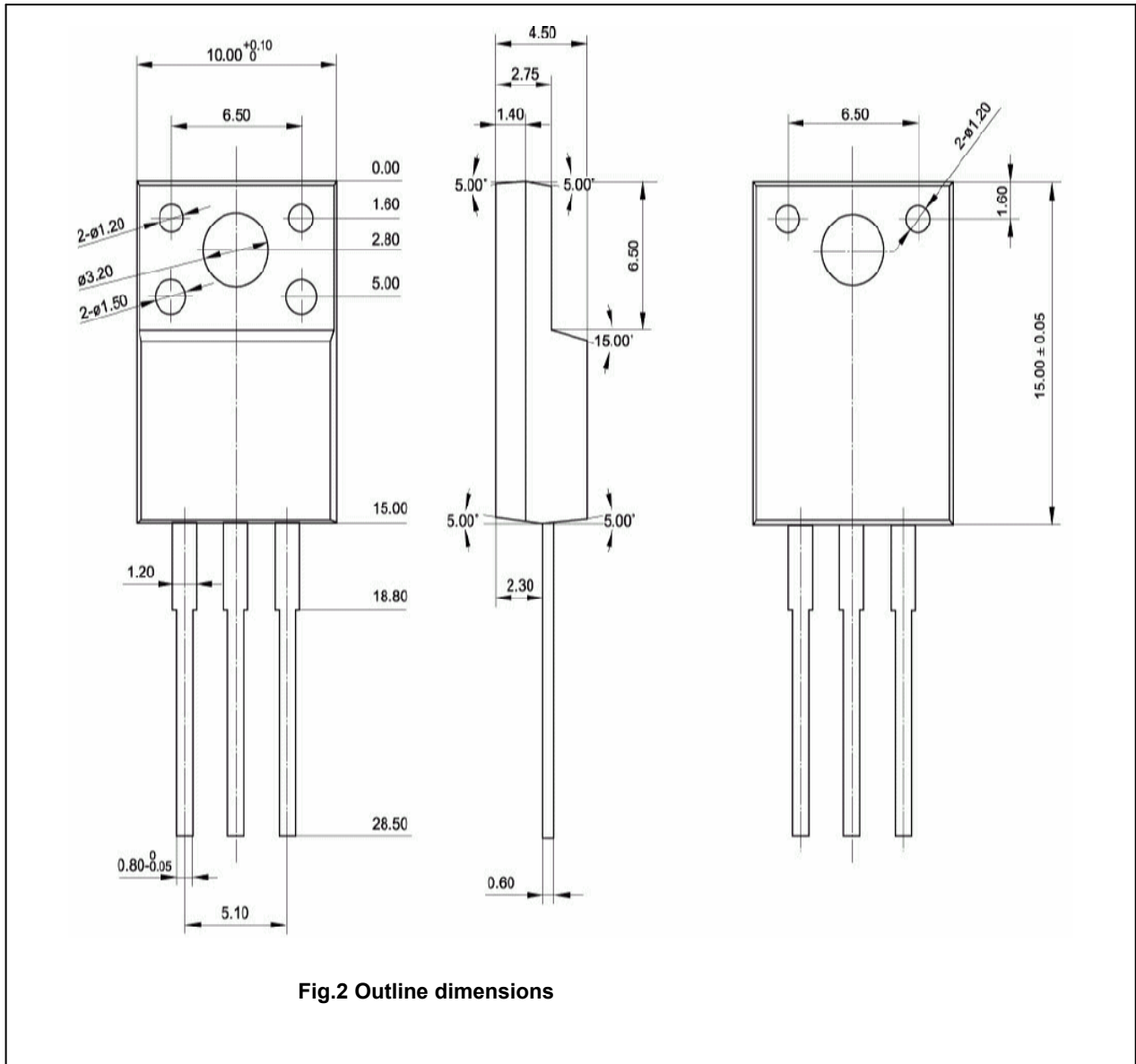


Fig.2 Outline dimensions

Silicon NPN Power Transistors

2SC4381 2SC4382

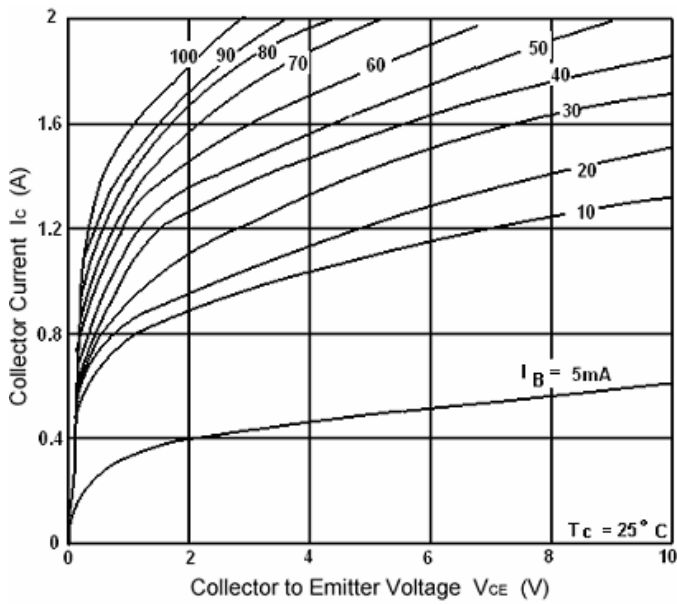


Fig.3 Static Characteristic

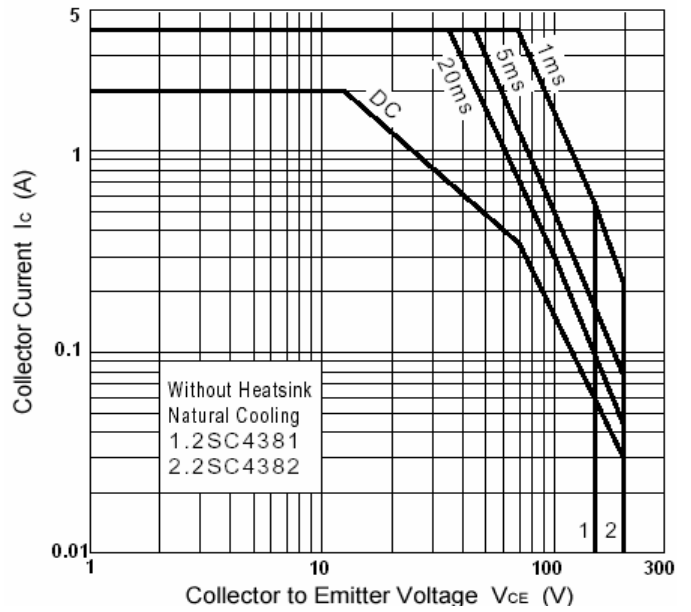


Fig.4 Safe Operating Area

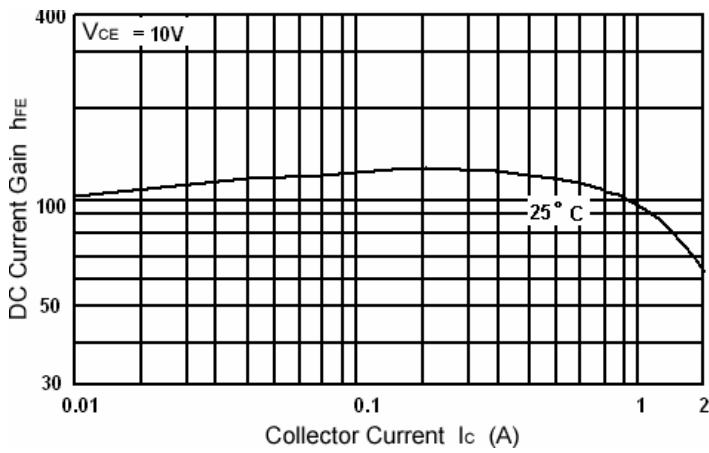


Fig.5 DC current Gain